



#### 80V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI

### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	I <sub>D</sub> T <sub>C</sub> = +25°C
80V	17mΩ @V <sub>GS</sub> = 10V	50A
80V	21mΩ @V <sub>GS</sub> = 4.5V	45A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Synchronous rectifiers
- Backlighting
- Power-management functions
- DC-DC converters

#### **Features**

- Rated to +175°C Ideal for High Ambient Temperature Environments
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH8012LPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

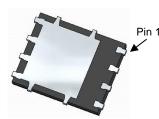
#### **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe;
   Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.097 grams (Approximate)

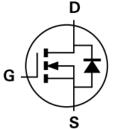


Top View

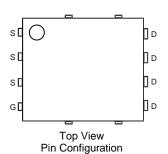




**Bottom View** 



Internal Schematic



#### Ordering Information (Note 4)

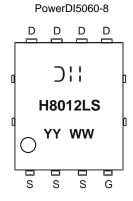
Dort Number	Dookogo	Packing		
Part Number	Package	Qty.	Carrier	
DMTH8012LPSQ-13	PowerDI5060-8	2500	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



# **Marking Information**



The Manufacturer's Marking H8012LS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 24 = 2024) WW = Week Code (01 to 53)

### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		$V_{DSS}$	80	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 5)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	lo	8 6	А
Continuous Drain Current, $V_{GS} = 10V$ (Note 6) $ T_C = +25^{\circ}C $ $ T_C = +70^{\circ}C $		lo	50 36	А
Maximum Continuous Body Diode Forward Current (Note 6)	Is	90	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		IDM	200	Α
Avalanche Current, L = 0.1mH		I <sub>AS</sub>	11.6	А
Avalanche Energy, L = 0.1mH		Eas	10.2	mJ

### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P <sub>D</sub>	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)		RθJA	57	°C/W
Total Power Dissipation (Note 6)	T <sub>C</sub> = +25°C	PD	100	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	1.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:



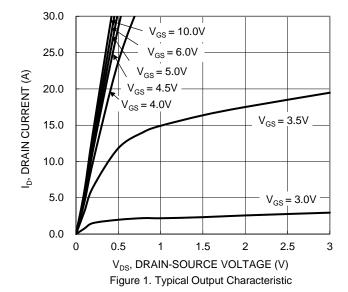
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	80	_	_	V	$V_{GS} = 0$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μΑ	$V_{DS} = 64V, V_{GS} = 0$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(TH)	1	_	3	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance	Danie ii	_	12.3	17	m0	V <sub>G</sub> S = 10V, I <sub>D</sub> = 12A	
Static Dialii-Source Off-Resistance	RDS(ON)	_	15.1	21	mΩ	$V_{GS} = 4.5V, I_{D} = 6A$	
Diode Forward Voltage	V <sub>SD</sub>	_	0.9	1.2	V	$V_{GS} = 0$ , $I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	2051	_		V <sub>DS</sub> = 40V, V <sub>GS</sub> = 0, f = 1MHz	
Output Capacitance	Coss	_	189.9	_	pF		
Reverse Transfer Capacitance	Crss	_	24.6	_			
Gate Resistance	Rg	_	0.44	_	Ω	$V_{DS} = 0$ , $V_{GS} = 0$ , $f = 1MHz$	
Total Gate Charge (VGS = 4.5V)	Qg	_	24.1	_			
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	46.8	_	nC	V <sub>DS</sub> = 40V, I <sub>D</sub> = 12A	
Gate-Source Charge	Qgs	_	6.9	_	IIC		
Gate-Drain Charge	Qgd	_	12.2	_			
Turn-On Delay Time	tD(ON)	_	5.8	_		$V_{DD} = 40V, V_{GS} = 10V,$ $I_{D} = 12A, R_{G} = 1.6\Omega$	
Turn-On Rise Time	t <sub>R</sub>	_	6.5	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	17.3	_	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	4.7	_			
Body Diode Reverse-Recovery Time	t <sub>RR</sub>	_	33.5	_	ns	L 124 di/dt 1004/up	
Body Diode Reverse-Recovery Charge	Q <sub>RR</sub>	_	38.9	_	nC	$I_F = 12A$ , di/dt = 100A/ $\mu$ s	

Notes:

<sup>7.</sup> Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.





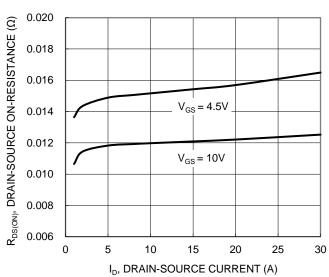


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

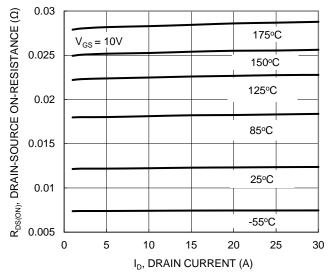


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

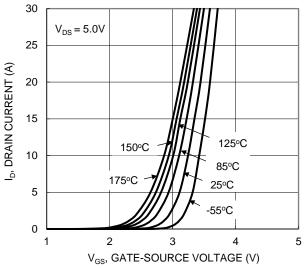


Figure 2. Typical Transfer Characteristic

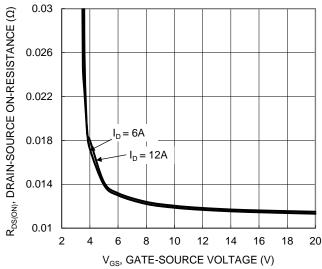


Figure 4. Typical Transfer Characteristic

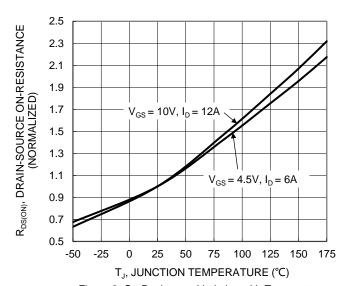


Figure 6. On-Resistance Variation with Temperature





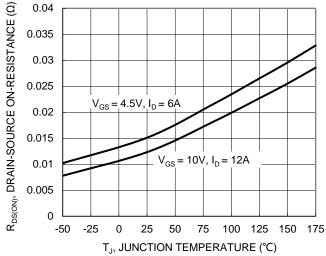
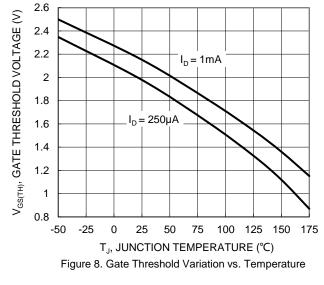


Figure 7. On-Resistance Variation with Temperature



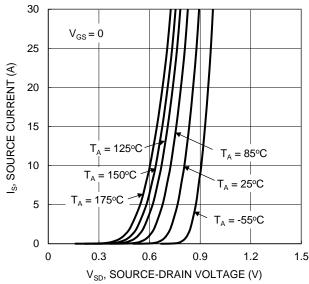


Figure 9. Diode Forward Voltage vs. Current

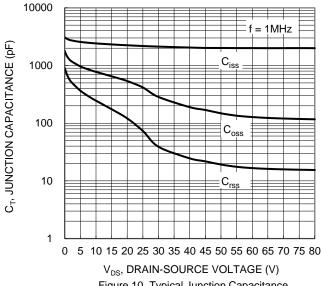
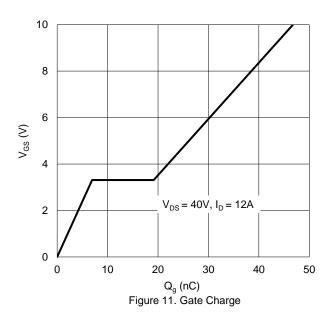


Figure 10. Typical Junction Capacitance



1000 R<sub>DS(ON)</sub> Limited 100 ID, DRAIN CURRENT (A) 10  $T_{J(Max)} = 175$ °C  $P_W = 100 \text{ms}^2$  $T_C = 25^{\circ}C$ Single Pulse **DUT** on Infinite Heatsink  $V_{GS} = 10V$ 0.01 0.1 100 10  $V_{DS}$ , DRAIN-SOURCE VOLTAGE (V)

Figure 12. SOA, Safe Operation Area



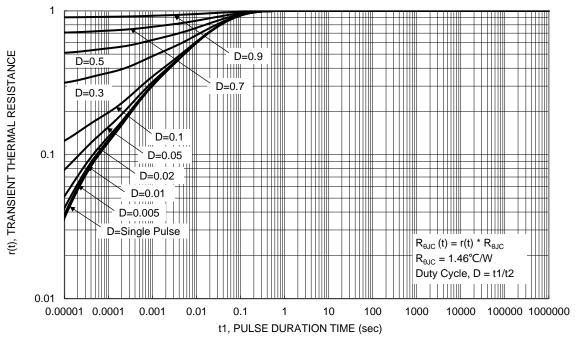


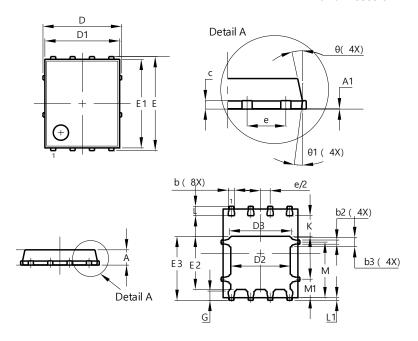
Figure 13. Transient Thermal Resistance



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8

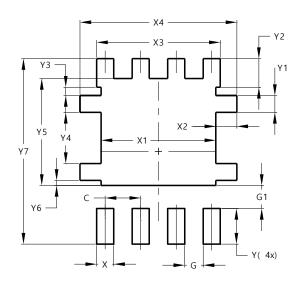


PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	1		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	,	5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	(	6.15 BSC	,		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC	;		
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12º	11º		
Θ1	6°	8º	7º		
Al	All Dimensions in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Y	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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